

LM26001B 1.5A Switching Regulator with High Efficiency Sleep Mode

Check for Samples: [LM26001B](#)

FEATURES

- High Efficiency Sleep Mode
- 40 μ A Typical I_q in Sleep Mode
- 10 μ A Typical I_q in Shutdown Mode
- 3.0V Minimum Input Voltage
- 4.0V to 18V Continuous Input Range
- 2.0% Reference Accuracy
- Cycle-by-Cycle Current Limit
- Adjustable Frequency (150 kHz to 500 kHz)
- Synchronizable to an External Clock
- Power Good Flag
- Forced PWM Function
- Adjustable Soft-Start
- HTSSOP-16 Exposed Pad Package
- Thermal Shut Down

APPLICATIONS

- Automotive Telematics
- Navigation Systems
- In-Dash Instrumentation
- Battery Powered Applications
- Stand-by Power for Home Gateways/Set-Top Boxes

DESCRIPTION

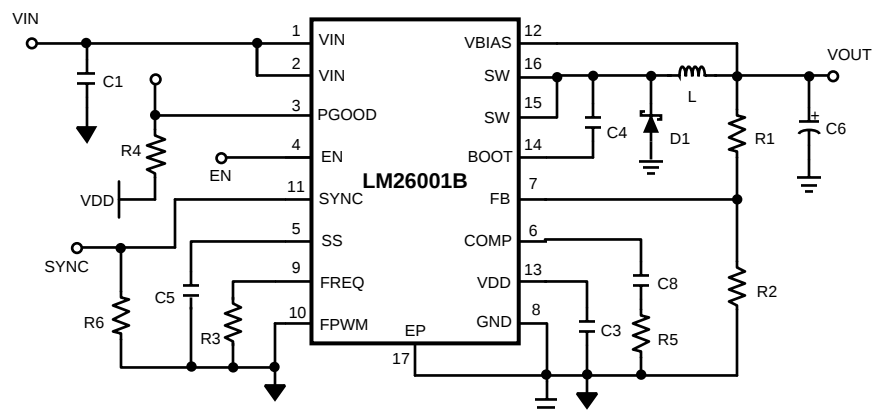
The LM26001B is a switching regulator designed for the high efficiency requirements of applications with stand-by modes. The device features a low-current sleep mode to maintain efficiency under light-load conditions and current-mode control for accurate regulation over a wide input voltage range. Quiescent current is reduced to 10 μ A typically in shutdown mode and less than 40 μ A in sleep mode. Forced PWM mode is also available to disable sleep mode.

The LM26001B can deliver up to 1.5A of continuous load current with a fixed current limit, through the internal N-channel switch. The part has a wide input voltage range of 4.0V to 18V and can operate with input voltages as low as 3V during line transients.

Operating frequency is adjustable from 150 kHz to 500 kHz with a single resistor and can be synchronized to an external clock.

Other features include Power good, adjustable soft-start, enable pin, input under-voltage protection, and an internal bootstrap diode for reduced component count.

Typical Application Circuit



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

Connection Diagram

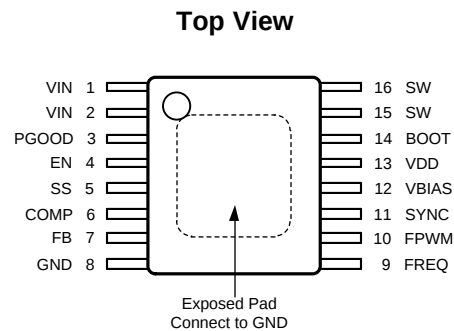


Figure 1. 16-Lead Exposed Pad HTSSOP Package
See Package Number PWP0016A

Pin Descriptions

Pin #	Pin Name	Description
1	VIN	Power supply input
2	VIN	Power supply input
3	PGOOD	Power Good pin. An open drain output which goes high when the output voltage is greater than 92% of nominal.
4	EN	Enable is an analog level input pin. When pulled below 0.8V, the device enters shutdown mode.
5	SS	Soft-start pin. Connect a capacitor from this pin to GND to set the soft-start time.
6	COMP	Compensation pin. Connect to a resistor capacitor pair to compensate the control loop.
7	FB	Feedback pin. Connect to a resistor divider between Vout and GND to set output voltage.
8	GND	Ground
9	FREQ	Frequency adjust pin. Connect a resistor from this pin to GND to set the operating frequency.
10	FPWM	FPWM is a logic level input pin. For normal operation, connect to GND. When pulled high, sleep mode operation is disabled.
11	SYNC	Frequency synchronization pin. Connect to an external clock signal for synchronized operation. SYNC must be pulled low for non-synchronized operation.
12	VBIAS	Connect to an external 3V or greater supply to bypass the internal regulator for improved efficiency. If not used, VBIAS should be tied to GND.
13	VDD	The output of the internal regulator. Bypass with a minimum 1.0 μ F capacitor.
14	BOOT	Bootstrap capacitor pin. Connect a 0.1 μ F minimum ceramic capacitor from this pin to SW to generate the gate drive bootstrap voltage.
15	SW	Switch pin. The source of the internal N-channel switch.
16	SW	Switch pin. The source of the internal N-channel switch.
EP	EP	Exposed Pad thermal connection. Connect to GND.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

Voltages from the indicated pins to GND:		
VIN		-0.3V to 20V
SW ⁽²⁾		-0.5V to 20V
VDD		-0.3V to 7V
VBIAS		-0.3V to 10V
FB		-0.3V to 6V
BOOT		SW-0.3V to SW+7V
PGOOD		-0.3V to 7V
FREQ		-0.3V to 7V
SYNC		-0.3V to 7V
EN		-0.3V to 20V
FPWM		-0.3V to 7V
SS		-0.3V to 7V
Storage Temperature		-65°C to +150°C
Power Dissipation ⁽³⁾		2.6 W
Recommended Lead Temperature	Vapor Phase (70s)	215°C
	Infrared (15s)	220°C
ESD Susceptibility ⁽⁴⁾	Machine Model	200V
	Human Body Model	2KV
	Charged Device Model	1kV

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) The absolute maximum specification applies to DC voltage. An extended negative voltage limit of -2V applies for a pulse of up to 1μs, and -1V for a pulse of up to 20μs.
- (3) The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J_MAX} , the junction-to-ambient thermal resistance, θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D_MAX} = (T_{J_MAX} - T_A) / \theta_{JA}$. The maximum power dissipation of 2.6W is determined using $T_A = 25^\circ\text{C}$, $\theta_{JA} = 38^\circ\text{C/W}$, and $T_{J_MAX} = 125^\circ\text{C}$.
- (4) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin. The charged device model is per JESD22-C101-C.

Operating Ratings⁽¹⁾

Operating Junction Temp.	-40°C to 125°C
Supply Voltage ⁽²⁾	3.0V to 18V

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) Below 4.0V input, power dissipation may increase due to increased $R_{DS(ON)}$. Therefore, a minimum input voltage of 4.0V is required to operate continuously within specification. A minimum of 3.9V (typical) is also required for startup.

Electrical Characteristics

Specifications in standard type are for $T_J = 25^\circ\text{C}$ only, and limits in boldface type apply over the junction temperature (T_J) range of -40°C to $+125^\circ\text{C}$. Unless otherwise stated, $V_{IN}=12\text{V}$. Minimum and Maximum limits are ensured through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^\circ\text{C}$, and are provided for reference purposes only⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
System						
$I_{SD}^{(2)}$	Shutdown Current	EN = 0V		10.8	20	μA
$I_{Q_Sleep_VB}^{(2)}$	Quiescent Current	Sleep mode, VBIAS = 5V		38	70	μA
$I_{Q_Sleep_VDD}$	Quiescent Current	Sleep mode, VBIAS = GND		75	125	μA
$I_{Q_PWM_VB}$	Quiescent Current	PWM mode, VBIAS = 5V		150	230	μA
$I_{Q_PWM_VDD}$	Quiescent Current	PWM mode, VBIAS = GND		0.65	0.85	mA
$I_{BIAS_Sleep}^{(2)}$	Bias Current	Sleep mode, VBIAS = 5V		33	85	μA
I_{BIAS_PWM}	Bias Current	PWM mode, VBIAS = 5V		0.5	0.70	mA
V_{FB}	Feedback Voltage	$5\text{V} < V_{IN} < 18\text{V}$	1.2093	1.234	1.2589	V
I_{FB}	FB Bias Current				± 200	nA
$\Delta V_{OUT}/\Delta V_{IN}$	Vout Line Regulation	$5\text{V} < V_{IN} < 18\text{V}$		0.001		%/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Vout Load Regulation	$0.8\text{V} < V_{COMP} < 1.15\text{V}$		0.07		%
VDD	VDD Output Voltage	$7\text{V} < V_{IN} < 18\text{V}$, $I_{VDD} = 0\text{ mA to } 5\text{ mA}$	5.50	5.95	6.50	V
I_{SS_Source}	Soft-Start Source Current		1.5	2.2	4.6	μA
V_{bias_th}	VBIAS On Voltage	Specified at $I_{BIAS} = 92.5\%$ of full value	2.64	2.9	3.07	V
Switching						
$R_{DS(ON)}$	Switch On Resistance	$I_{SW} = 1\text{A}$	0.12	0.2	0.42	Ω
I_{SW_off}	Switch Off State Leakage Current	$V_{IN} = 18\text{V}$, $V_{SW} = 0\text{V}$		0.002	5.0	μA
f_{SW}	Switching Frequency	RFREQ = 62k, 124k, 240k			± 10	%
V_{FREQ}	FREQ Voltage			1.0		V
f_{SW_range}	Switching Frequency Range		150		500	kHz
V_{SYNC}	Sync Pin Threshold	SYNC rising		1.2	1.6	V
		SYNC falling	0.8	1.1		
	Sync Pin Hysteresis			114		mV
I_{SYNC}	SYNC Leakage Current			6		nA
F_{SYNC_UP}	Upper frequency synchronization range	As compared to nominal f_{SW}			+30	%
F_{SYNC_DN}	Lower frequency synchronization range	As compared to nominal f_{SW}			-20	%
T_{OFFMIN}	Minimum Off-time			365		ns
T_{ONMIN}	Minimum On-time			155		ns
TH_{SLEEP_HYS}	Sleep Mode Threshold Hysteresis	VFB rising, % of TH_{WAKE}		101.2		%
TH_{WAKE}	Wake Up Threshold	Measured at falling FB, COMP = 0.6V		1.234		V
I_{BOOT}	BOOT Pin Leakage Current	BOOT = 16V, SW = 10V		0.0006	5.0	μA

- (1) All room temperature limits are 100% production tested. All limits at temperature extremes are specified through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).
- (2) I_Q and I_{SD} specify the current into the V_{IN} pin. I_{BIAS} is the current into the VBIAS pin when the VBIAS voltage is greater than 3V. All quiescent current specifications apply to non-switching operation.

Electrical Characteristics (continued)

Specifications in standard type are for $T_J = 25^\circ\text{C}$ only, and limits in boldface type apply over the junction temperature (T_J) range of -40°C to $+125^\circ\text{C}$. Unless otherwise stated, $V_{in}=12\text{V}$. Minimum and Maximum limits are ensured through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^\circ\text{C}$, and are provided for reference purposes only⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Protection						
I_{LIMPK}	Peak Current Limit		1.80	2.5	3.25	A
V_{FB_SC}	Short Circuit Frequency Foldback Threshold	Measured at FB falling		0.87		V
F_{min_sc}	Min Frequency in Foldback	$V_{FB} < 0.3\text{V}$		71		kHz
V_{TH_PGOOD}	Power Good Threshold	Measured at FB, PGOOD rising	89	92	95	%
	PGOOD Hysteresis		2	7	8	%
I_{PGOOD_HI}	PGOOD Leakage Current	$PGOOD = 5\text{V}$		0.2		nA
R_{DS_PGOOD}	PGOOD On Resistance	PGOOD sink current = $500\text{ }\mu\text{A}$		64		Ω
V_{UVLO}	Under-Voltage Lock-Out Threshold	Vin falling , shutdown, $V_{DD} = V_{IN}$	2.60	2.9	3.20	V
		Vin rising, soft-start, $V_{DD} = V_{IN}$	3.60	3.9	4.20	
TSD	Thermal Shutdown Threshold			160		$^\circ\text{C}$
θ_{JA}	Thermal Resistance	Power dissipation = 1W , 0 lfpm air flow		38		$^\circ\text{C/W}$
Logic						
V_{th_EN}	Enable Threshold voltage		0.8	1.2	1.4	V
	Enable Hysteresis			120		mV
I_{EN_Source}	EN Source Current	$EN = 0\text{V}$		4.5		μA
V_{TH_FPWM}	FPWM Threshold		0.8	1.2	1.6	V
I_{FPWM}	FPWM Leakage Current	$FPWM = 5\text{V}$		35		nA
EA						
g_m	Error Amp Trans-Conductance		400	670	1000	μmho
I_{COMP}	COMP Source Current	$V_{COMP} = 0.9\text{V}$		56		μA
	COMP Sink Current	$V_{COMP} = 0.9\text{V}$		56		μA
V_{COMP}	COMP Pin Voltage Range		0.64		1.27	V

Typical Performance Characteristics

Unless otherwise specified the following conditions apply: $V_{in} = 12V$, $T_J = 25^\circ C$.

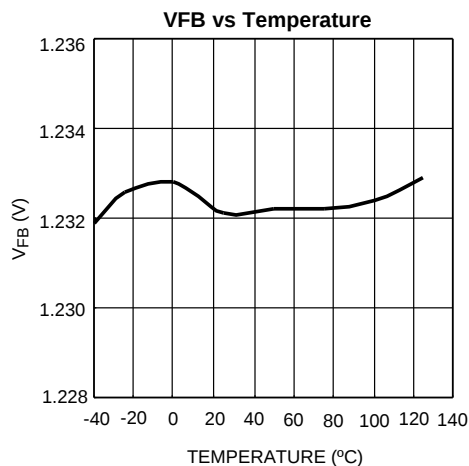


Figure 2.

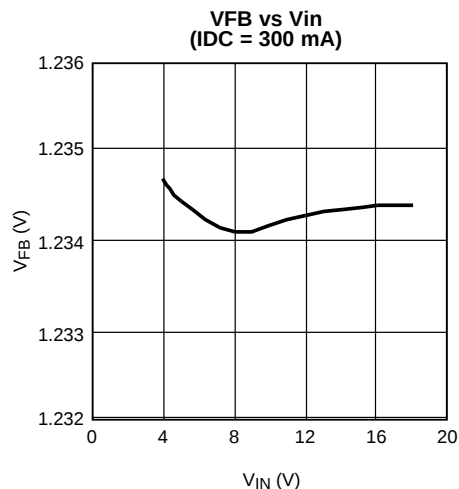


Figure 3.

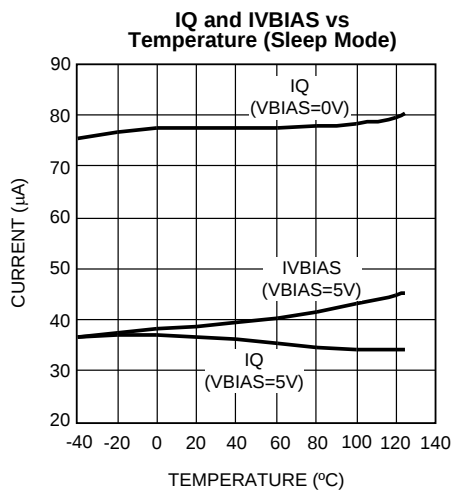


Figure 4.

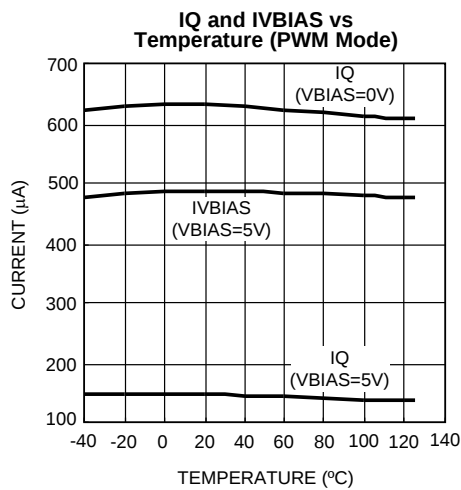


Figure 5.

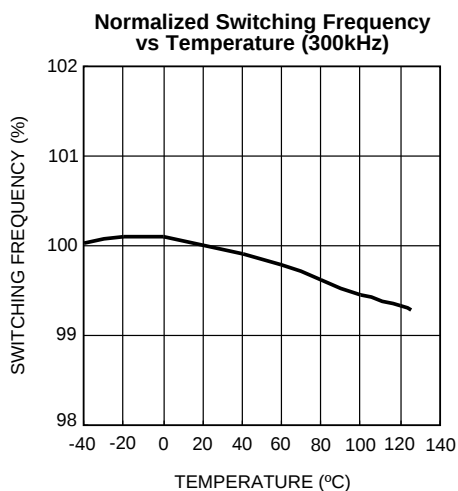


Figure 6.

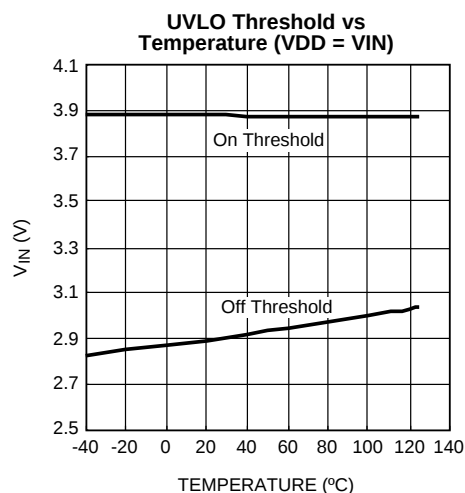


Figure 7.

Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply: $V_{in} = 12V$, $T_J = 25^{\circ}C$.

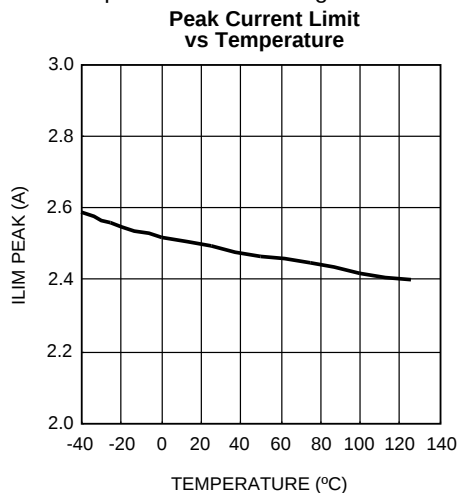


Figure 8.

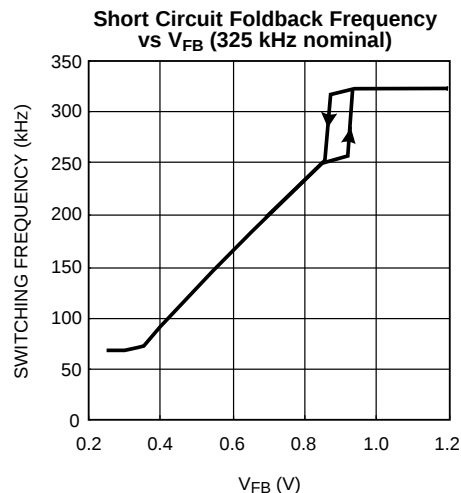


Figure 9.

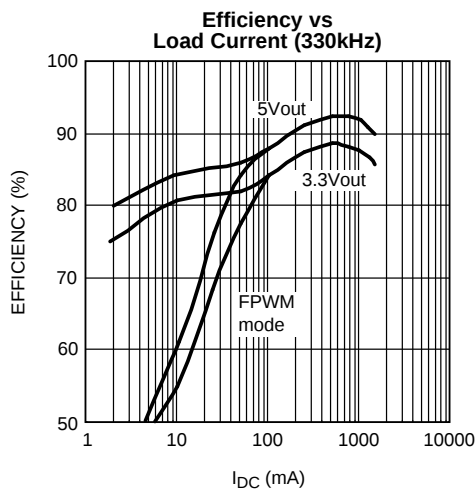


Figure 10.

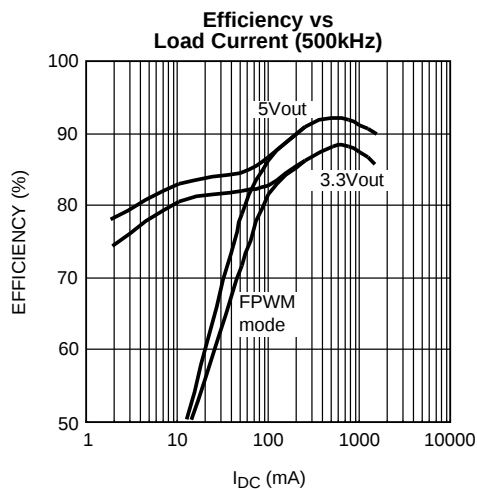


Figure 11.

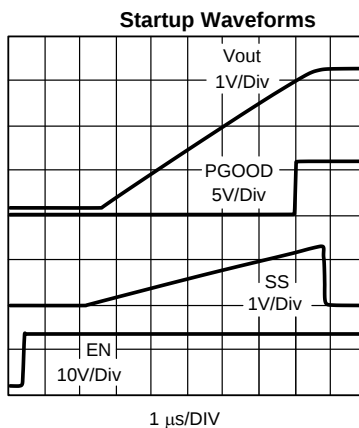


Figure 12.

Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply: $V_{in} = 12V$, $T_J = 25^\circ C$.

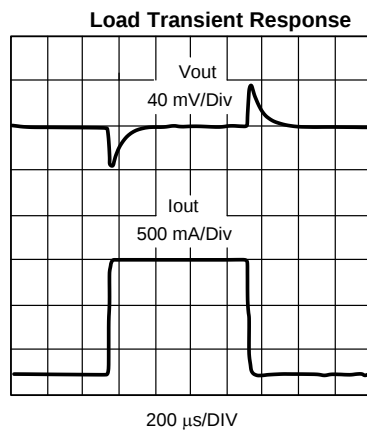


Figure 13.

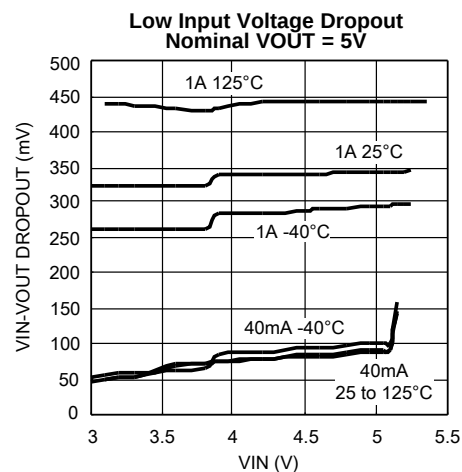
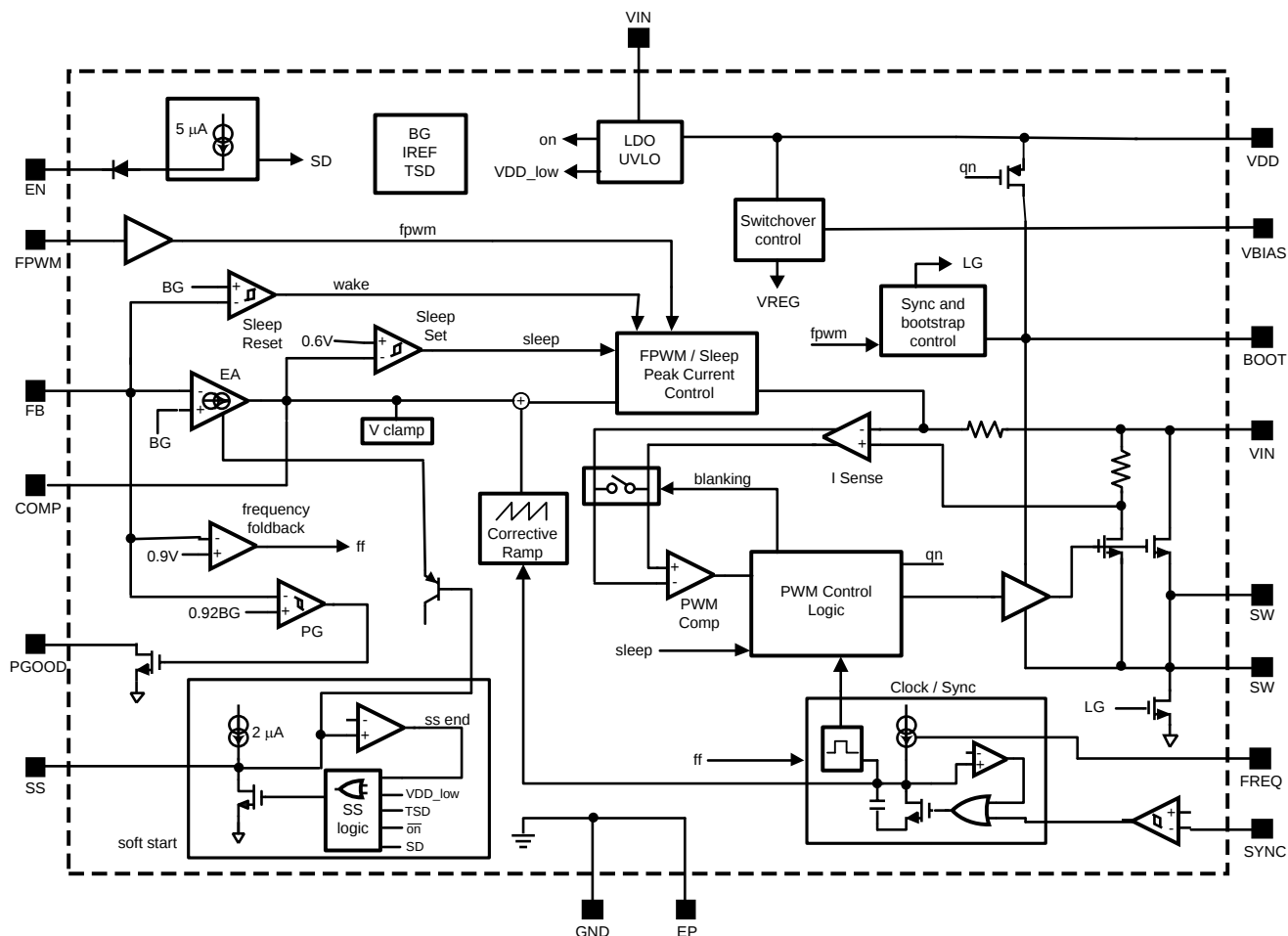


Figure 14.

Block Diagram



Operation Description

GENERAL

The LM26001B is a current mode PWM buck regulator. At the beginning of each clock cycle, the internal high-side switch turns on, allowing current to ramp up in the inductor. The inductor current is internally monitored during each switching cycle. A control signal derived from the inductor current is compared to the voltage control signal at the COMP pin, derived from the feedback voltage. When the inductor current reaches the threshold, the high-side switch is turned off and inductor current ramps down. While the switch is off, inductor current is supplied through the catch diode. This cycle repeats at the next clock cycle. In this way, duty cycle and output voltage are controlled by regulating inductor current. Current mode control provides superior line and load regulation. Other benefits include cycle by cycle current limiting and a simplified compensation scheme. Typical PWM waveforms are shown in [Figure 15](#).

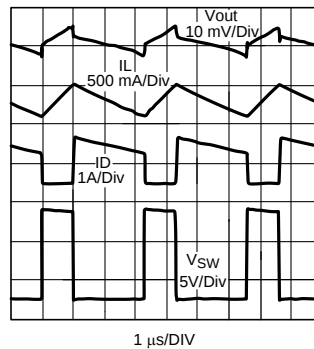


Figure 15. PWM Waveforms
1A Load, Vin = 12V

SLEEP MODE

In light load conditions, the LM26001B automatically switches into sleep mode for improved efficiency. As loading decreases, the voltage at FB increases and the COMP voltage decreases. When the COMP voltage reaches the 0.6V (typical) clamp threshold, and the FB voltage rises 1% above nominal, sleep mode is enabled and switching stops. The regulator remains in sleep mode until the FB voltage falls to the reset threshold, at which point switching resumes. This 1% FB window limits the corresponding output ripple to approximately 1% of nominal output voltage. The sleep cycle will repeat until load current is increased. Figure 16 shows typical switching and output voltage waveforms in sleep mode.

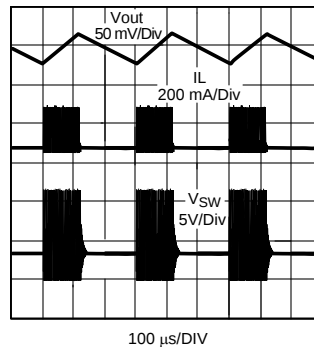


Figure 16. Sleep Mode Waveforms
25mA Load, Vin = 12V

In sleep mode, quiescent current is reduced to less than 40 μ A when not switching. The DC sleep mode threshold can be calculated according to the equation below:

$$I_{\text{sleep}} = \left[I_{\text{min}} + 0.13 \mu \left[\frac{V_{\text{in}} - V_{\text{out}}}{L} \right]^2 \right] \times \left[\frac{f_{\text{sw}} \times L}{D \times 2 \times (V_{\text{in}} - V_{\text{out}})} \right]$$

where

- $I_{\text{min}} = I_{\text{lim}}/16$ (2.5A/16 typically) and $D = \text{duty cycle}$, defined as $(V_{\text{out}} + V_{\text{diode}})/V_{\text{in}}$ (1)

When load current increases above this limit, the LM26001B is forced back into PWM operation. The sleep mode threshold varies with frequency, inductance, and duty cycle as shown in Figure 17.

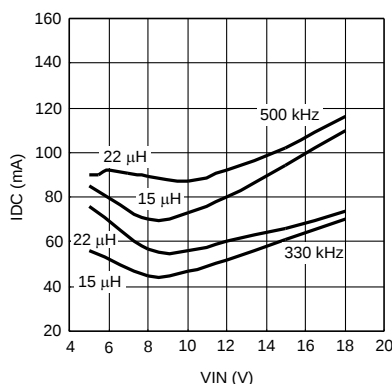


Figure 17. Sleep Mode Threshold vs Vin
Vout = 3.3V

FPWM

Pulling the FPWM pin high disables sleep mode and forces the LM26001B to always operate in PWM mode. Light load efficiency is reduced in PWM mode, but switching frequency remains stable. The FPWM pin can be connected to the VDD pin to pull it high. In FPWM mode, under light load conditions, the regulator operates in discontinuous conduction mode (DCM). In discontinuous conduction mode, current through the inductor starts at zero and ramps up to its peak, then ramps down to zero again. Until the next cycle, the inductor current remains at zero. At nominal load currents, in FPWM mode, the device operates in continuous conduction mode, where positive current always flows in the inductor. Typical discontinuous operation waveforms are shown below.

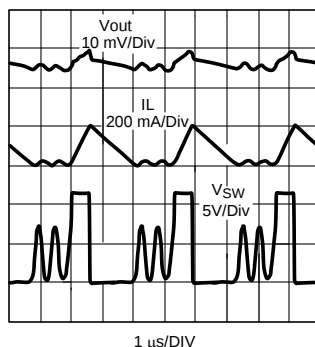


Figure 18. Discontinuous Mode Waveforms
75mA Load, Vin = 12V

At very light load, in FPWM mode, the LM26001B may enter sleep mode. This is to prevent an over-voltage condition from occurring. However, the FPWM sleep threshold is much lower than in normal operation.

ENABLE

The LM26001B provides a shutdown function via the EN pin to disable the device when the output voltage does not need to be maintained. EN is an analog level input with typically 120 mV of hysteresis. The device is active when the EN pin is above 1.2V (typical) and in shutdown mode when EN is below this threshold. When EN goes high, the internal VDD regulator turns on and charges the VDD capacitor. When VDD reaches 3.9V (typical), the soft-start pin begins to source current. In shutdown mode, the VDD regulator shuts down and total quiescent current is reduced to 10 μA (typical). Because the EN pin sources 4.5 μA (typical) of pull-up current, this pin can be left open or connected to VIN for always-on operation. When open, EN will be pulled up to VIN.

SOFT-START

The soft-start feature provides a controlled output voltage ramp up at startup. This reduces inrush current and eliminates output overshoot at turn-on. The soft-start pin, SS, must be connected to GND through a capacitor. At power-on, enable, or UVLO recovery, an internal 2.2 μ A (typical) current charges the soft-start capacitor. During soft-start, the error amplifier output voltage is controlled by both the soft-start voltage and the feedback loop. As the SS pin voltage ramps up, the duty cycle increases proportional to the soft-start ramp, causing the output voltage to ramp up. The rate at which the duty cycle increases depends on the capacitance of the soft-start capacitor. The higher the capacitance, the slower the output voltage ramps up. The soft-start capacitor value can be calculated with the following equation:

$$C_{ss} = \frac{I_{ss} \times t_{ss}}{1.234V} \quad (2)$$

Where t_{ss} is the desired soft-start time and I_{ss} is the soft-start source current. During soft-start, current limit and synchronization remain in effect, while sleep mode and frequency foldback are disabled. Soft-start mode ends when the SS pin voltage reaches 1.23V typical. At this point, output voltage control is transferred to the FB pin and the SS pin is discharged.

CURRENT LIMIT

The peak current limit is set internally by directly measuring peak inductor current through the internal switch. To ensure accurate current sensing, VIN should be bypassed with a minimum 1 μ F ceramic capacitor placed directly at the pin.

When the inductor current reaches the current limit threshold, the internal FET turns off immediately allowing inductor current to ramp down until the next cycle. This reduction in duty cycle corresponds to a reduction in output voltage.

The current limit comparator is disabled for less than 100ns at the leading edge for increased immunity to switching noise.

Because the current limit monitors peak inductor current, the DC load current limit threshold varies with inductance and frequency. Assuming a minimum current limit of 1.80A, maximum load current can be calculated as follows:

$$I_{load_max} = 1.80A - \frac{I_{ripple}}{2}$$

where

- I_{ripple} is the peak-to-peak inductor ripple current, calculated as
$$I_{ripple} = \frac{(V_{in} - V_{out}) \times V_{out}}{f_{sw} \times L \times V_{in}} \quad (3)$$

To find the worst case (lowest) current limit threshold, use the maximum input voltage and minimum current limit specification.

During high over-current conditions, such as output short circuit, the LM26001B employs frequency foldback as a second level of protection. If the feedback voltage falls below the short circuit threshold of 0.9V, operating frequency is reduced, thereby reducing average switch current. This is especially helpful in short circuit conditions, when inductor current can rise very high during the minimum on-time. Frequency reduction begins at 20% below the nominal frequency setting. The minimum operating frequency in foldback mode is 71 kHz typical.

If the FB voltage falls below the frequency foldback threshold during frequency synchronized operation, the SYNC function is disabled. Operating frequency versus FB voltage in short circuit conditions is shown in the [Typical Performance Characteristics](#) section.

In conditions where the on time is close to minimum (less than 200nsec typically), such as high input voltage and high switching frequency, the current limit may not function properly. This is because the current limit circuit cannot reduce the on-time below minimum which prevents entry into frequency foldback mode. There are two ways to ensure proper current limit and foldback operation under high input voltage conditions. First, the operating frequency can be reduced to increase the nominal on time. Second, the inductor value can be increased to slow the current ramp and reduce the peak over-current.

FREQUENCY ADJUSTMENT AND SYNCHRONIZATION

The switching frequency of the LM26001B can be adjusted between 150 kHz and 500 kHz using a single external resistor. This resistor is connected from the FREQ pin to ground as shown in the [Typical Application Circuit](#). The resistor value can be calculated with the following empirically derived equation:

$$R_{FREQ} = (6.25 \times 10^{10}) \times f_{SW}^{-1.042} \quad (4)$$

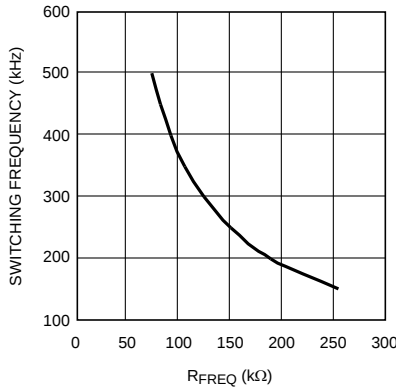


Figure 19. Switching Frequency vs R_FREQ

The switching frequency can also be synchronized to an external clock signal using the SYNC pin. The SYNC pin allows the operating frequency to be varied above and below the nominal frequency setting. The adjustment range is from 30% above nominal to 20% below nominal. External synchronization requires a 1.2V (typical) peak signal level at the SYNC pin. The FREQ resistor must always be connected to initialize the nominal operating frequency. The operating frequency is synchronized to the falling edge of the SYNC input. When SYNC goes low, the high-side switch turns on. This allows any duty cycle to be used for the sync signal when synchronizing to a frequency higher than nominal. When synchronizing to a lower frequency, however, there is a minimum duty cycle requirement for the SYNC signal, given in the equation below:

$$\text{Sync_Dmin} \geq 1 - \frac{f_{\text{sync}}}{f_{\text{nom}}} \quad (5)$$

Where f_{nom} is the nominal switching frequency set by the FREQ resistor, and f_{sync} is a square wave. If the SYNC pin is not used, it must be pulled low for normal operation. A 10kΩ pull-down resistor is recommended to protect against a missing sync signal. Although the LM26001B is designed to operate at up to 500 kHz, maximum load current may be limited at higher frequencies due to increased temperature rise. See the [Thermal Considerations](#) section.

VBIAS

The VBIAS pin is used to bypass the internal regulator which provides the bias voltage to the LM26001B. When the VBIAS pin is connected to a voltage greater than 3V, the internal regulator automatically switches over to the VBIAS input. This reduces the current into VIN (I_q) and increases system efficiency. Using the VBIAS pin has the added benefit of reducing power dissipation within the device.

For most applications where $3V < V_{\text{out}} < 10V$, VBIAS can be connected to V_{out} . If not used, VBIAS should be tied to GND.

If VBIAS drops below 2.9V (typical), the device automatically switches over to supply the internal bias voltage from V_{in} .

Total device input current is the sum of I_q , gate drive current, and VBIAS current, plus some negligible current into the FB pin. Total minimum input supply current can be calculated as shown below:

$$I_{\text{input}} = I_q + I_{QG} + \left(\frac{I_{\text{BIAS}} \times D}{\text{eff}} \right)$$

where

- I_{QG} is the gate drive current, calculated as $I_{QG} = (4.6 \times 10^{-9}) \times f_{SW}$ (6)

Total supply input current varies according to load, system efficiency, and operating frequency. To calculate minimum input current during sleep mode, use $I_{q_Sleep_VB}$, and I_{BIAS_SLEEP} .

For input current in PWM mode, use the same equation, with $I_{q_PWM_VB}$, and I_{BIAS_PWM} .

If VBIAS is connected to ground, use the same equation with the I_{bias} term eliminated and either $I_{q_Sleep_VDD}$ or $I_{q_PWM_VDD}$.

LOW VIN OPERATION AND UVLO

The LM26001B is designed to remain operational during short line transients when input voltage may drop as low as 3.0V. Minimum nominal operating input voltage is 4.0V. Below this voltage, switch $R_{DS(ON)}$ increases, due to the lower gate drive voltage from VDD. The minimum voltage required at VDD is approximately 3.5V for normal operation within specification.

VDD can also be used as a pull-up voltage for functions such as PGOOD and FPWM. Note that if VDD is used externally, the pin is not recommended for loads greater than 1 mA.

If the input voltage approaches the nominal output voltage, the duty cycle is maximized to hold up the output voltage. In this mode of operation, once the duty cycle reaches its maximum, the LM26001B can skip a maximum of seven off pulses, effectively increasing the duty cycle and thus minimizing the dropout from input to output. Typical off-pulse skipping waveforms are shown below.

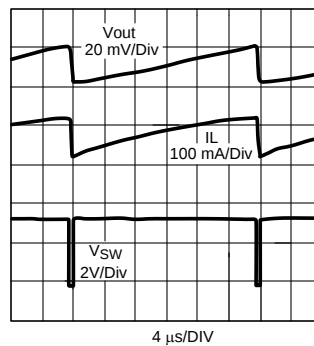


Figure 20. Off-pulse Skipping Waveforms
 $V_{in} = 3.5V$, $V_{nom} = 3.3V$, $f_{nom} = 305kHz$

UVLO is sensed at both VIN and VDD, and is activated when either voltage falls below 2.9V (typical). Although VDD is typically less than 200mV below VIN, it will not discharge through VIN. Therefore when the VIN voltage drops rapidly, VDD may remain high, especially in sleep mode. For fast line voltage transients, using a larger capacitor at the VDD pin can help to hold off a UVLO shutdown by extending the VDD discharge time. By holding up VDD, a larger cap can also reduce the $R_{DS(ON)}$ (and dropout voltage) in low VIN conditions. Alternately, under heavy loading the VDD voltage can fall several hundred mV below VIN. In this case, UVLO may be triggered by VDD even though the VIN voltage is above the UVLO threshold.

When UVLO is activated the LM26001B enters a standby state in which VDD remains charged. As input voltage and VDD voltage rise above 3.9V (typical) the device will restart from softstart mode.

PGOOD

A power good pin, PGOOD, is available to monitor the output voltage status. The pin is internally connected to an open drain MOSFET, which remains open while the output voltage is within operating range. PGOOD goes low (low impedance to ground) when the output falls below 85% of nominal or EN is pulled low. When the output voltage returns to within 92% of nominal, as measured at the FB pin, PGOOD returns to a high state. For improved noise immunity, there is a 5μs delay between the PGOOD threshold and the PGOOD pin going low.

Design Information

EXAMPLE CIRCUIT

Figure 21 shows a complete typical application schematic. The components have been selected based on the design criteria given in the following sections.

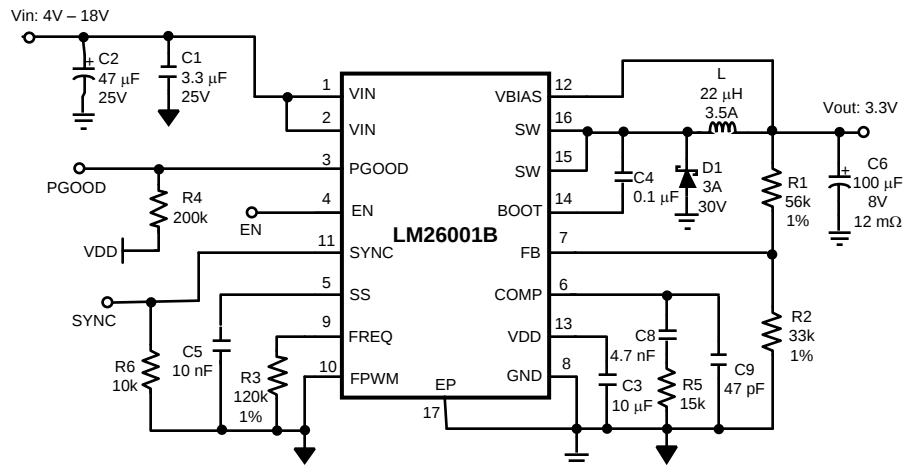


Figure 21. Example Circuit
1.5A Max, 305 kHz

SETTING OUTPUT VOLTAGE

The output voltage is set by the ratio of a voltage divider at the FB pin as shown in the [Typical Application Circuit](#). The resistor values can be determined by the following equation:

$$R2 = \frac{R1}{\left(\frac{V_{out}}{V_{fb}} - 1\right)}$$

where

- $V_{fb} = 1.234V$ typically (7)

A maximum value of 150kΩ is recommended for the sum of R1 and R2.

As input voltage decreases towards the nominal output voltage, the LM26001B can skip up to seven off-pulses as described in the [Low Vin Operation](#) section. In low output voltage applications, if the on-time reaches T_{on_MIN} , the device will skip on-pulses to maintain regulation. There is no limit to the number of pulses that are skipped. In this mode of operation, however, output ripple voltage may increase slightly.

INDUCTOR

The output inductor should be selected based on inductor ripple current. The amount of inductor ripple current compared to load current, or ripple content, is defined as I_{ripple}/I_{load} . Ripple content should be less than 40%. Inductor ripple current, I_{ripple} , can be calculated as shown below:

$$I_{ripple} = \frac{(V_{in} - V_{out}) \times V_{out}}{f_{sw} \times L \times V_{in}} \quad (8)$$

Larger ripple content increases losses in the inductor and reduces the effective current limit.

Larger inductance values result in lower output ripple voltage and higher efficiency, but a slightly degraded transient response. Lower inductance values allow for smaller case size, but the increased ripple lowers the effective current limit threshold.

Remember that inductor value also affects the sleep mode threshold as shown in [Figure 17](#).

When choosing the inductor, the saturation current rating must be higher than the maximum peak inductor current and the RMS current rating should be higher than the maximum load current. Peak inductor current, I_{peak} , is calculated as:

$$I_{peak} = I_{load} + \frac{I_{ripple}}{2} \quad (9)$$

For example, at a maximum load of 1.5A and a ripple content of 33%, peak inductor current is equal to 1.75A which is safely below the minimum current limit of 1.80A. By increasing the inductor size, ripple content and peak inductor current are lowered, which increases the current limit margin.

The size of the output inductor can also be determined using the desired output ripple voltage, V_{rip} . The equation to determine the minimum inductance value based on V_{rip} is as follows:

$$L_{MIN} = \frac{(V_{in} - V_{out}) \times V_{out} \times R_e}{V_{in} \times f_{sw} \times V_{rip}}$$

where

- R_e is the ESR of the output capacitors
 - V_{rip} is a peak-to-peak value
- (10)

This equation assumes that the output capacitors have some amount of ESR. It does not apply to ceramic output capacitors.

If this method is used, ripple content should still be verified to be less than 40%.

OUTPUT CAPACITOR

The primary criterion for selecting an output capacitor is equivalent series resistance, or ESR.

ESR (R_e) can be selected based on the requirements for output ripple voltage and transient response. Once an inductor value has been selected, ripple voltage can be calculated for a given R_e using the equation above for L_{min} . Lower ESR values result in lower output ripple.

R_e can also be calculated from the following equation:

$$R_{eMAX} = \frac{\Delta V_t}{\Delta I_t}$$

where

- ΔV_t is the allowed voltage excursion during a load transient
 - ΔI_t is the maximum expected load transient
- (11)

If the total ESR is too high, the load transient requirement cannot be met, no matter how large the output capacitance.

If the ESR criteria for ripple voltage and transient excursion cannot be met, more capacitors should be used in parallel.

For non-ceramic capacitors, the minimum output capacitance is of secondary importance, and is determined only by the load transient requirement.

If there is not enough capacitance, the output voltage excursion will exceed the maximum allowed value even if the maximum ESR requirement is met. The minimum capacitance is calculated as follows:

$$C_{MIN} = \frac{L \times \left(\Delta V_t - \sqrt{(\Delta V_t)^2 - (\Delta I_t \times R_e)^2} \right)}{V_{out} \times R_e^2} \quad (12)$$

It is assumed the total ESR, R_e , is no greater than R_{eMAX} . Also, it is assumed that L has already been selected.

Generally speaking, the output capacitance requirement decreases with R_e , ΔI_t , and L . A typical value greater than 100 μF works well for most applications.

INPUT CAPACITOR

In a switching converter, very fast switching pulse currents are drawn from the input rail. Therefore, input capacitors are required to reduce noise, EMI, and ripple at the input to the LM26001B. Capacitors must be selected that can handle both the maximum ripple RMS current at highest ambient temperature as well as the maximum input voltage. The equation for calculating the RMS input ripple current is shown below:

$$I_{rms} = \frac{I_{load} \times \sqrt{V_{out} \times (V_{in} - V_{out})}}{V_{in}} \quad (13)$$

For noise suppression, a ceramic capacitor in the range of 1.0 μ F to 10 μ F should be placed as close as possible to the VIN pin.

A larger, high ESR input capacitor should also be used. This capacitor is recommended for damping input voltage spikes during power on and for holding up the input voltage during transients. In low input voltage applications, line transients may fall below the UVLO threshold if there is not enough input capacitance. Both tantalum and electrolytic type capacitors are suitable for the bulk capacitor. However, large tantalums may not be available for high input voltages and their working voltage must be derated by at least 2X.

BOOTSTRAP

The drive voltage for the internal switch is supplied via the BOOT pin. This pin must be connected to a ceramic capacitor, Cboot, from the switch node, shown as C4 in the typical application. The LM26001B provides the VDD voltage internally, so no external diode is needed. A minimum value of 0.1 μ F is recommended for Cboot. Smaller values may result in insufficient hold up time for the drive voltage and increased power dissipation.

During low Vin operation, when the on-time is extended, the bootstrap capacitor is at risk of discharging. If the Cboot capacitor is discharged below approximately 2.5V, the LM26001B enters a high frequency re-charge mode. The Cboot cap is re-charged via the LG synchronous FET shown in the [Block Diagram](#). Switching returns to normal when the Cboot cap has been recharged.

CATCH DIODE

When the internal switch is off, output current flows through the catch diode. Alternately, when the switch is on, the diode sees a reverse voltage equal to Vin. Therefore, the important parameters for selecting the catch diode are peak current and peak inverse voltage. The average current through the diode is given by:

$$I_{DAVE} = I_{load} \times (1-D) \quad (14)$$

Where D is the duty cycle, defined as Vout/Vin. The catch diode conducts the largest currents during the lowest duty cycle. Therefore IDAVE should be calculated assuming maximum input voltage. The diode should be rated to handle this current continuously. For over-current or short circuit conditions, the catch diode should be rated to handle peak currents equal to the peak current limit.

The peak inverse voltage rating of the diode must be greater than maximum input voltage.

A Schottky diode must be used. It's low forward voltage maximizes efficiency and BOOT voltage, while also protecting the SW pin against large negative voltage spikes

COMPENSATION

The purpose of loop compensation is to ensure stable operation while maximizing dynamic performance. Stability can be analyzed with loop gain measurements, while dynamic performance is analyzed with both loop gain and load transient response. Loop gain is equal to the product of control-output transfer function (power stage) and the feedback transfer function (the compensation network).

For stability purposes, our target is to have a loop gain slope that is -20dB /decade from a very low frequency to beyond the crossover frequency. Also, the crossover frequency should not exceed one-fifth of the switching frequency, i.e. 60 kHz in the case of 300 kHz switching frequency.

For dynamic purposes, the higher the bandwidth, the faster the load transient response. A large DC gain means high DC regulation accuracy (i.e. DC voltage changes little with load or line variations). To achieve this loop gain, the compensation components should be set according to the shape of the control-output bode plot. A typical plot is shown in [Figure 22](#) below.

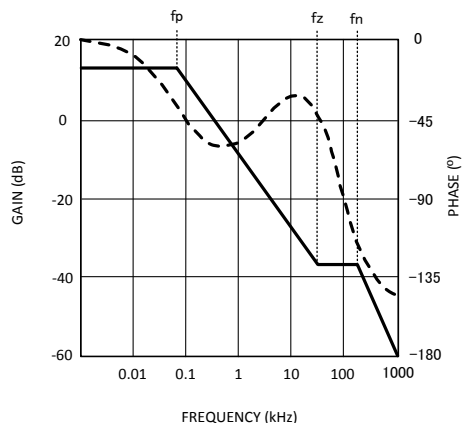


Figure 22. Control-Output Transfer Function

The control-output transfer function consists of one pole (f_p), one zero (f_z), and a double pole at f_n (half the switching frequency).

Referring to [Figure 22](#), the following should be done to create a -20dB /decade roll-off of the loop gain:

1. Place a pole at 0Hz (f_{pc})
2. Place a zero at f_p (f_{zc})
3. Place a second pole at f_z (f_{pc1})

The resulting feedback (compensation) bode plot is shown below in [Figure 23](#). Adding the control-output response to the feedback response will then result in a nearly continuous -20db/decade slope.

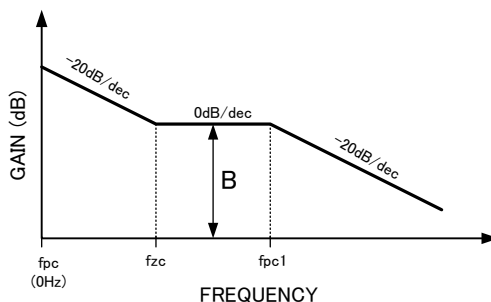


Figure 23. Feedback Transfer Function

The control-output corner frequencies can be determined approximately by the following equations:

$$f_z = \frac{1}{2\pi \times R_e \times C_o} \quad (15)$$

$$f_p = \frac{1}{10 \times \pi \times R_o \times C_o} + \frac{0.5}{2 \times \pi \times L \times f_{sw} \times C_o} \quad (16)$$

$$f_n = \frac{f_{sw}}{2}$$

where

- C_o is the output capacitance
- R_o is the load resistance
- R_e is the output capacitor ESR
- f_{sw} is the switching frequency

(17)

The effects of slope compensation and current sense gain are included in this equation. However, the equation is an approximation intended to simplify loop compensation calculations. To derive the exact transfer function, use 0.2V/V sense amp gain and 36mVp-p slope compensation.

Since f_p is determined by the output network, it shifts with loading. Determine the range of frequencies (f_{pmin}/f_{pmax}) across the expected load range. Then determine the compensation values as described below and shown in [Figure 24](#).

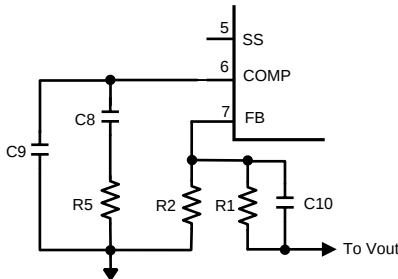


Figure 24. Compensation Network

1. The compensation network automatically introduces a low frequency pole (f_{pc}), which is close to 0Hz.
2. Once the f_p range is determined, R_5 should be calculated using:

$$R_5 = \frac{B}{g_m} \times \left(\frac{R_1 + R_2}{R_2} \right)$$

where

- B is the desired feedback gain in v/v between f_p and f_z
 - g_m is the transconductance of the error amplifier
- (18)

A gain value around 10dB (3.3v/v) is generally a good starting point. Bandwidth increases with increasing values of R_5 .

3. Next, place a zero (f_{zc}) near f_p using C_8 . C_8 can be determined with the following equation:

$$C_8 = \frac{1}{2 \times \pi \times f_{pMAX} \times R_5}$$

(19)

The selected value of C_8 should place f_{zc} within a decade above or below f_{pmax} , and not less than f_{pmin} . A higher C_8 value (closer to f_{pmin}) generally provides a more stable loop, but too high a value will slow the transient response time. Conversely, a smaller C_8 value will result in a faster transient response, but lower phase margin.

4. A second pole (f_{pc1}) can also be placed at f_z . This pole can be created with a single capacitor, C_9 . The minimum value for this capacitor can be calculated by:

$$C_9 = \frac{1}{2 \times \pi \times f_z \times R_5}$$

(20)

C_9 may not be necessary in all applications. However if the operating frequency is being synchronized below the nominal frequency, C_9 is recommended. Although it is not required for stability, C_9 is very helpful in suppressing noise.

A phase lead capacitor can also be added to increase the phase and gain margins. The phase lead capacitor is most helpful for high input voltage applications or when synchronizing to a frequency greater than nominal. This capacitor, shown as C_{10} in [Figure 24](#), should be placed in parallel with the top feedback resistor, R_1 . C_{10} introduces an additional zero and pole to the compensation network. These frequencies can be calculated as shown below:

$$f_{zff} = \frac{1}{2 \times \pi \times R_1 \times C_{10}}$$

(21)

$$f_{pff} = \frac{f_{zff} \times V_{out}}{V_{fb}} \quad (22)$$

A phase lead capacitor will boost loop phase around the region of the zero frequency, f_{zff} . f_{zff} should be placed somewhat below the f_{pz1} frequency set by C9. However, if C10 is too large, it will have no effect.

PCB Layout

Good board layout is critical for switching regulators such as the LM26001B. First, the ground plane area must be sufficient for thermal dissipation purposes, and second, appropriate guidelines must be followed to reduce the effects of switching noise.

Switch mode converters are very fast switching devices. In such devices, the rapid increase of input current combined with parasitic trace inductance generates unwanted Ldi/dt noise spikes at the SW node and also at the VIN node. The magnitude of this noise tends to increase as the output current increases. This parasitic spike noise may turn into electromagnetic interference (EMI), and can also cause problems in device performance. Therefore, care must be taken in layout to minimize the effect of this switching noise.

The current sensing circuit in current mode devices can be easily affected by switching noise. This noise can cause duty cycle jitter which leads to increased spectral noise. Although the LM26001B has 100ns blanking time at the beginning of every cycle to ignore this noise, some noise may remain after the blanking time. Following the important guidelines below will help minimize switching noise and its effect on current sensing.

The switch node area should be as small as possible. The catch diode, input capacitors, and output capacitors should be grounded to a large ground plane, with the bulk input capacitor grounded as close as possible to the catch diode anode. Additionally, the ground area between the catch diode and bulk input capacitor is very noisy and should be somewhat isolated from the rest of the ground plane.

A ceramic input capacitor must be connected as close as possible to the VIN pin and grounded close to the GND pin. Often this capacitor is most easily located on the bottom side of the pcb. If placement close to the GND pin is not practical, the ceramic input capacitor can also be grounded close to the catch diode ground. The above layout recommendations are illustrated below in [Figure 25](#).

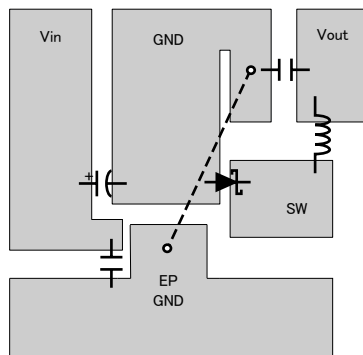


Figure 25. Example PCB Layout

It is a good practice to connect the EP, GND pin, and small signal components (COMP, FB, FREQ) to a separate ground plane, shown in [Figure 25](#) as EP GND, and in the schematics as a signal ground symbol. Both the exposed pad and the GND pin must be connected to ground. This quieter plane should be connected to the high current ground plane at a quiet location, preferably near the Vout ground as shown by the dashed line in [Figure 25](#).

The EP GND plane should be made as large as possible, since it is also used for thermal dissipation. Several vias can be placed directly below the EP to increase heat flow to other layers when they are available. The recommended via hole diameter is 0.3mm.

The trace from the FB pin to the resistor divider should be short and the entire feedback trace must be kept away from the inductor and switch node. See Application Note [AN-1229](#) for more information regarding PCB layout for switching regulators.

Thermal Considerations and TSD

Although the LM26001B has a built in current limit, at ambient temperatures above 80°C, device temperature rise may limit the actual maximum load current. Therefore, temperature rise must be taken into consideration to determine the maximum allowable load current.

Temperature rise is a function of the power dissipation within the device. The following equations can be used to calculate power dissipation (PD) and temperature rise, where total PD is the sum of FET switching losses, FET DC losses, drive losses, I_q , and VBIAS losses:

$$PD_{TOTAL} = P_{SW_{AC}} + P_{SW_{DC}} + P_{QG} + P_{Iq} + P_{VBIAS} \quad (23)$$

$$P_{SW_{AC}} = V_{in} \times I_{load} \times f_{sw} \times \left(\frac{V_{in} \times 10^{-9}}{1.33} \right) \quad (24)$$

$$P_{SW_{DC}} = D \times I_{load}^2 \times (0.2 + 0.00065 \times (T_j - 25)) \quad (25)$$

$$P_{QG} = V_{in} \times 4.6 \times 10^{-9} \times f_{sw} \quad (26)$$

$$P_{Iq} = V_{in} \times I_q \quad (27)$$

$$P_{VBIAS} = V_{bias} \times I_{VBIAS} \quad (28)$$

Given this total power dissipation, junction temperature can be calculated as follows:

$$T_j = T_a + (PD_{TOTAL} \times \theta_{JA})$$

where

- $\theta_{JA} = 38^\circ\text{C/W}$ (typically) when using a multi-layer board with a large copper plane area (29)

θ_{JA} varies with board type and metallization area.

To calculate the maximum allowable power dissipation, assume $T_j = 125^\circ\text{C}$. To ensure that junction temperature does not exceed the maximum operating rating of 125°C , power dissipation should be verified at the maximum expected operating frequency, maximum ambient temperature, and minimum and maximum input voltage. The calculated maximum load current is based on continuous operation and may be exceeded during transient conditions.

If the power dissipation remains above the maximum allowable level, device temperature will continue to rise. When the junction temperature exceeds its maximum, the LM26001B engages Thermal Shut Down (TSD). In TSD, the part remains in a shutdown state until the junction temperature falls to within normal operating limits. At this point, the device restarts in soft-start mode.

REVISION HISTORY

Changes from Revision A (April 2013) to Revision B	Page
• Changed layout of National Data Sheet to TI format	21

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM26001BMH/NOPB	Active	Production	HTSSOP (PWP) 16	92 TUBE	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	L26001 BMH
LM26001BMH/NOPB.A	Active	Production	HTSSOP (PWP) 16	92 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	L26001 BMH
LM26001BMH/NOPB.B	Active	Production	HTSSOP (PWP) 16	92 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	L26001 BMH
LM26001BMHX/NOPB	Active	Production	HTSSOP (PWP) 16	2500 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	L26001 BMH
LM26001BMHX/NOPB.A	Active	Production	HTSSOP (PWP) 16	2500 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	L26001 BMH
LM26001BMHX/NOPB.B	Active	Production	HTSSOP (PWP) 16	2500 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	L26001 BMH

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM26001BMHX/NOPB	HTSSOP	PWP	16	2500	330.0	12.4	6.95	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



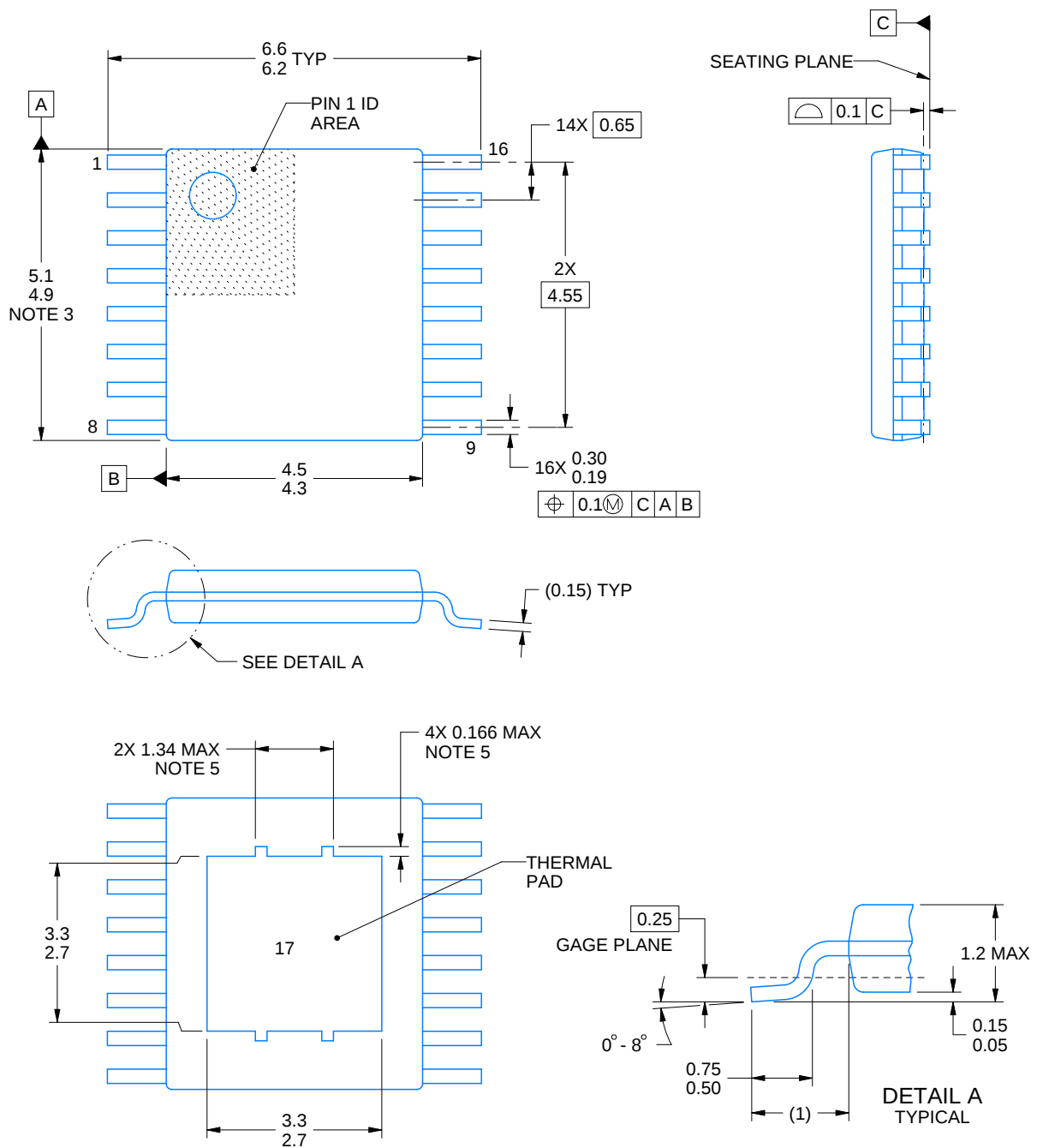
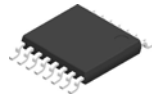
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM26001BMHX/NOPB	HTSSOP	PWP	16	2500	367.0	367.0	35.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LM26001BMH/NOPB	PWP	HTSSOP	16	92	495	8	2514.6	4.06
LM26001BMH/NOPB.A	PWP	HTSSOP	16	92	495	8	2514.6	4.06
LM26001BMH/NOPB.B	PWP	HTSSOP	16	92	495	8	2514.6	4.06



4214868/A 02/2017

NOTES:

PowerPAD is a trademark of Texas Instruments.

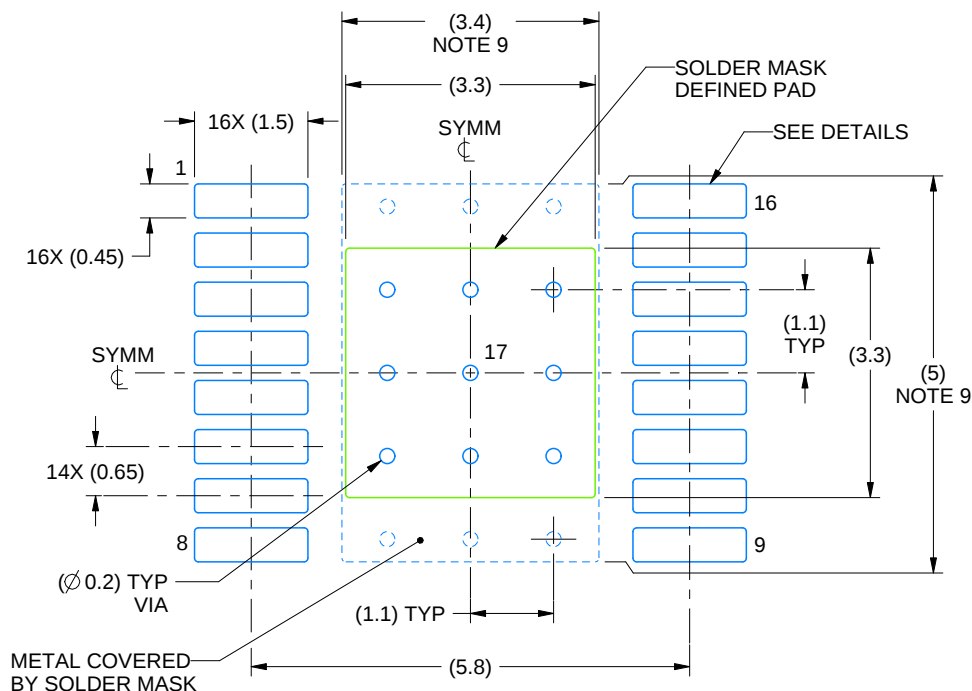
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may not be present.

EXAMPLE BOARD LAYOUT

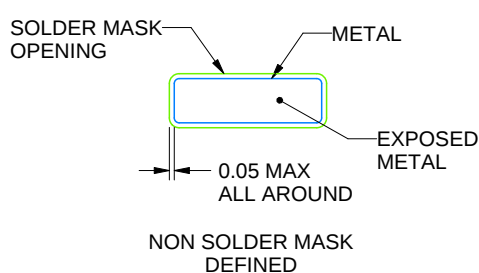
PWP0016A

PowerPAD™ HTSSOP - 1.2 mm max height

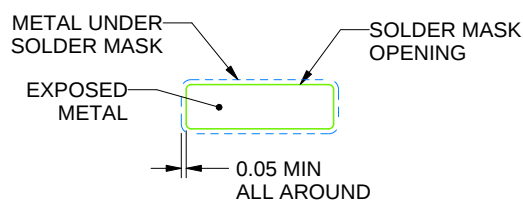
PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:10X



NON SOLDER MASK
DEFINED



SOLDER MASK
DEFINED

SOLDER MASK DETAILS
PADS 1-16

4214868/A 02/2017

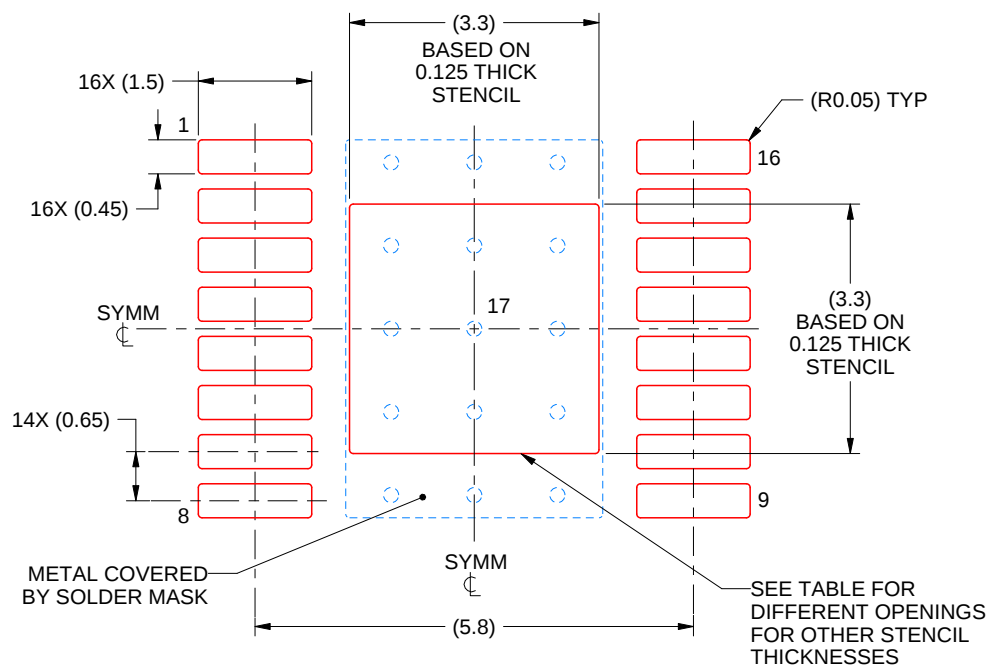
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.

PWP0016A

PowerPAD™ HTSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.69 X 3.69
0.125	3.3 X 3.3 (SHOWN)
0.15	3.01 X 3.01
0.175	2.79 X 2.79

4214868/A 02/2017

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated